TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SD2414(SM)

High Current Switching Applications Power Amplifier Applications

• Low collector saturation voltage: V_{CE} (sat) = 0.5 V (max) (at I_C = 4 A)

Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	100	V	
Collector-emitter voltage		V _{CEO}	80	V	
Emitter-base voltage		V _{EBO}	5	V	
Collector current		Ι _C	7	А	
Base current		Ι _Β	1	А	
Collector power dissipation	Ta = 25°C	Pc	1.5	W	
	Tc = 25°C	ГC	40		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

10.3MAX 1.32 10.6 MAX 5 ŝ 0.76 2.54 S C .7 MAX 1. BASE 2. COLLECTOR (HEAT SINK) 3. EMITTER JEDEC ____ JEITA _ TOSHIBA 2-10S2

Weight: 1.4 g (typ.)

Unit: mm

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current		I _{CBO}	V _{CB} = 100 V, I _E = 0		—	5	μA
Emitter cut-off current		I _{EBO}	V _{EB} = 5 V, I _C = 0		_	5	μA
Collector-emitter breakdown voltage		V (BR) CEO	I _C = 50 mA, I _B = 0	80		_	V
DC current gain		h _{FE (1)}	V _{CE} = 1 V, I _C = 1 A	100	_	320	
		h _{FE (2)}	V _{CE} = 1 V, I _C = 4 A	30	_	_	
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 4 A, I _B = 0.4 A	_	0.25	0.5	V
Base-emitter saturation voltage		V _{BE (sat)}	I _C = 4 A, I _B = 0.4 A	_	0.9	1.4	V
Transition frequency		fT	V _{CE} = 4 V, I _C = 1 A		10	_	MHz
Collector output capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	200	_	pF
Switching time	Turn-on time	t _{on}	20 μ s Input $\stackrel{ B1}{\rightarrow}$ $\downarrow \square$ $\downarrow \square$ \square \square \square \square \square \square \square	_	0.4	_	
	Storage time	t _{stg}		_	2.5	_	μs
	Fall time	t _f		_	0.5	_	

Marking



Explanation of Lot No.

Month of manufacture (January to December are denoted by letters A to L respectively.) Year of manufacture (Last decimal digit of the year of manufacture)

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Safe Operating Area IC max (pul 10 1 ms -IC max .(continu E 10 Collector current IC DC operation Tc = 25°C 100 ms 0.5 0.3 *: Single nonrepetitive pulse Tc = 25°C Curves must be derated linearly with increase in temperature. VCEO max 0.1 3 5 10 50 30 100 Collector-emitter voltage V_{CE} (V)

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